

# monolithic dual n-channel JFETs designed for . . .

- FET Input Amplifiers
- Low and Medium Frequency Amplifiers
- Impedance Converters

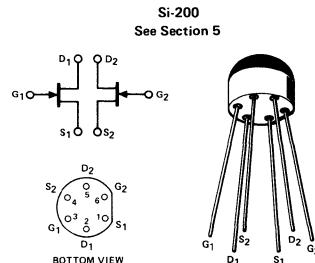
## ABSOLUTE MAXIMUM RATINGS (25°C)

Gate-To-Gate Voltage	.....	+40 V
Gate-Drain or Gate-Source Voltage	.....	-40 V
Gate Current	.....	50 mA
Total Package Dissipation (25°C Free-Air Temperature)	.....	350 mW
Power Derating (to +125°C)	.....	3.5 mW/°C
Storage Temperature Range	.....	-55 to +125°C
Operating Temperature Range	.....	-55 to +125°C
Lead Temperature (1/16" from case for 10 seconds)	.....	300°C

## Performance Curves NQP See Section 4

### BENEFITS

- Minimum System Error and Calibration  
10 mV Offset Maximum (E400,  
E401)  
80 dB Typical CMRR
- Low Drift with Temperature  
10  $\mu\text{V}/^\circ\text{C}$  (E400)
- Simplifies Amplifier Design  
Output Conductance  $< 10 \mu\text{mho}$



## ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

Characteristic	E400			E401			E402			Unit	Test Conditions
	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max		
1 Igss				-200			-200			-200	pA
2 Vgs(off)				-1.0	-4.5	-1.0	-4.5	-1.0		-4.5	V
3 T <sub>A</sub>				-40		-40			-40		
4 I <sub>DSS</sub>				0.5	5.0	0.5	5.0	0.5		5.0	mA
5 I <sub>G</sub>				-200			-200			-200	pA
6 V <sub>GS</sub>				-0.2	-4.0	-0.2	-4.0	-0.2		-4.0	V
7 g <sub>fs</sub>	1,000	4,000	1,000	4,000	1,000	4,000	4,000				
8	600	1,600	600	1,600	600	1,600	1,600				
9 D <sub>gds</sub>		35			35			35			
10		10			10			10			
11 A <sub>Ciss</sub>		4.5			4.5			4.5			pF
12 C <sub>crss</sub>		1.2			1.2			1.2			
13 $\bar{e}_n$		13			13			13			$\frac{\text{nV}}{\text{VHz}}$
14 M <sub>A</sub>  V <sub>GS1</sub> -V <sub>GS2</sub>				10			10			20	mV
T <sub>A</sub>											
15 C <sub>H</sub>  ΔV <sub>GS1</sub> -V <sub>GS2</sub>				10			25			50	$\mu\text{V}/^\circ\text{C}$
H ΔT											
16 N <sub>G</sub> CMRR		80			80			70			dB
G											

NOTES:  
1. Approximately doubles for every 10°C increase in T<sub>A</sub>.  
2. Pulse test duration = 300  $\mu\text{sec}$ ; duty cycle  $\leq 3\%$ .  
3. Measured at end points, T<sub>A</sub> and T<sub>B</sub>.

NQP

$$4. \text{ CMRR} = 20 \log_{10} \left[ \frac{\Delta V_{DD}}{\Delta V_{GS1}-V_{GS2}} \right], \Delta V_{DD} = 10 \text{ V}.$$